

Low Voltage 16-Bit D-TYPE FLIP-FLOP with 5V Tolerant Inputs and Outputs

The TC74LCX16374AFT is a high performance CMOS 16-bit D-TYPE FLIP-FLOP. Designed for use in 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation.

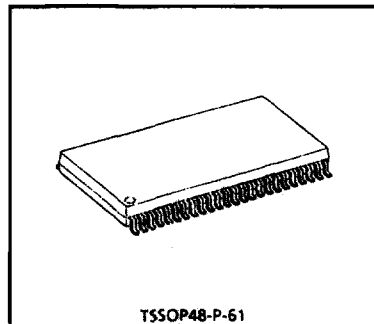
The device is designed for low voltage (3.3V) V_{CC} applications, but it could be used to interface to 5V supply environment for both inputs and outputs.

This 16-bit flip-flop is controlled by a clock input (CK) and an output enable input (\overline{OE}) which are common to each byte. It can be used as two 8-bit flip-flops or one 16-bit flip-flop. When the \overline{OE} input is high, the outputs are in a high impedance state.

All inputs are equipped with protection circuits against static discharge.

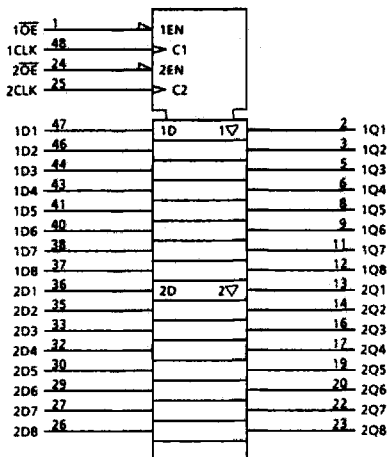
Features

- Low Voltage Operation: $V_{CC} = 2.0 \sim 3.6V$
- High Speed: $t_{pd} = 7.0ns$ (Max.) at $V_{CC} = 3.0 \sim 3.6V$
- Output Current: $I_{OH}/I_{OL} = 24mA$ (Min.) $V_{CC} = 3.0V$
- Latch up Performance: $\pm 500mA$
- Package: TSSOP (Thin Shrink Small Outline Package)
- Power down protection is provided on all inputs and outputs.

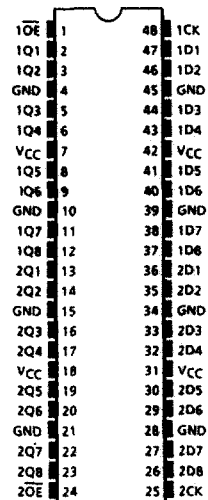


TSSOP48-P-61

Weight : 0.25 g (Typ.)



IEC Logic Symbol



(TOP VIEW)

Pin Assignment

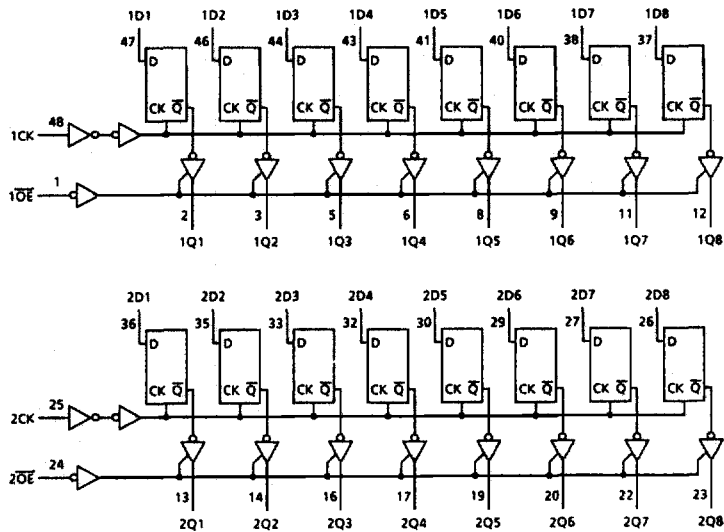
Truth Table

Input			Output
10E	1CK	1D1 - 1D8	1Q1 - 1Q8
H	X	X	Z
L	⌋	X	Qn
L	f	L	L
L	f	H	H

Input			Output
20E	2CK	2D1 - 2D8	2Q1 - 2Q8
H	X	X	Z
L	⌋	X	Qn
L	f	L	L
L	f	H	H

X : Don't Care
 Z : High Impedance
 Qn : No Change

System Diagram



Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Power Supply Voltage	V_{CC}	-0.5 ~ 7.0	V
DC Input Voltage	V_{IN}	-0.5 ~ 7.0	V
DC Bus I/O Voltage	$V_{I/O}$	-0.5 ~ 7.0 (*1)	V
		-0.5 - V_{CC} + 0.5 (*2)	
Input Diode Current	I_{IK}	-50	mA
Output Diode Current	I_{OK}	±50 (*3)	mA
DC Output Current	I_{OUT}	±50	mA
Power Dissipation	P_D	400	mW
DC V_{CC} /Ground Current Per Supply Pin	I_{CC}/I_{GND}	±100	mA
Storage Temperature	T_{stg}	-65 ~ 150	°C

(*1) Off-State

(*2) High or Low State. I_{OUT} absolute maximum rating must be observed(*3) $V_{OUT} < GND$, $V_{OUT} > V_{CC}$ **Recommended Operating Range**

Parameter	Symbol	Rating	Unit
Supply Voltage	V_{CC}	2.0 ~ 3.6	V
		1.5 ~ 3.6 (*4)	
Input Voltage	V_{IN}	0 ~ 5.5	V
Bus I/O Voltage	$V_{I/O}$	0 ~ 5.5 (*5)	V
		0 - V_{CC} (*6)	
Output Current	I_{OH}/I_{OL}	±24 (*7)	mA
		±12 (*8)	
Operating Temperature	T_{opr}	-40 ~ 85	°C
Input Rise and Fall Time	dt/dv	0 ~ 10 (*9)	ns/V

(*4) Data Retention Only

(*5) Off-State

(*6) High or Low State

(*7) $V_{CC} = 3.0 \sim 3.6V$ (*8) $V_{CC} = 2.7 \sim 3.0V$ (*9) $V_{IN} = 0.8 \sim 2.0V$, $V_{CC} = 3.0V$

Electrical Characteristics

DC Characteristics (Ta = -40 ~ 85°C)

Parameter	Symbol	Test Condition		V _{CC} (V)	Min.	Max.	Unit	
Input Voltage	"H" Level	V _{IH}		2.7 - 3.6	2.0	-	V	
	"L" Level	V _{IL}		2.7 - 3.6	-	0.8	V	
Output Voltage	"H" Level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -100μA	2.7 - 3.6	V _{CC} - 0.2	-	V
				I _{OH} = -12mA	2.7	2.2	-	
				I _{OH} = -18mA	3.0	2.4	-	
				I _{OH} = -24mA	3.0	2.2	-	
"L" Level	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 100μA	2.7 - 3.6	-	0.2	V	
			I _{OL} = 16mA	3.0	-	0.4		
			I _{OL} = 12mA	2.7	-	0.4		
			I _{OL} = 24mA	3.0	-	0.55		
Input Leakage Current	I _{IN}	V _{IN} = 0 - 5.5V	2.7 - 3.6	-	±5.0	μA		
3-State Output Off-State Current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{IN} = 0 - 5.5V	2.7 - 3.6	-	±5.0	μA		
Power Off Leakage Current	I _{OFF}	V _{IN} /V _{OUT} = 5.5V	0	-	10.0	μA		
Quiescent Supply Current	I _{CC}	V _{IN} = V _{CC} or GND	2.7 - 3.6	-	20.0	μA		
		V _{IN} /V _{OUT} = 3.6 - 5.5V	2.7 - 3.6	-	±20.0			
Increase in I _{CC} per Input	ΔI _{CC}	V _{IH} = V _{CC} - 0.6V	2.7 - 3.6	-	500	μA		

AC Electrical Characteristics (Ta = -40 ~85°C)

Parameter	Symbol	Test Condition	V _{CC} (V)	Min.	Max.	Unit
Maximum Clock Frequency	t _{DLH} t _{DHL}	(Fig. 1, 2)	2.7	-	-	ns
			3.3±0.3	170	-	
Propagation Delay Time (CK - Q)	t _{DLH} t _{DHL}	(Fig. 1, 2)	2.7	-	8.0	ns
			3.3±0.3	1.5	7.0	
3-State Output Enable Time	t _{pZL} t _{pZH}	(Fig. 1, 3)	2.7	-	8.2	ns
			3.3±0.3	1.5	7.2	
3-State Output Disable Time	t _{pLZ} t _{pHZ}	(Fig. 1, 3)	2.7	-	8.2	ns
			3.3±0.3	1.5	7.2	
Minimum Pulse Width (CK)	t _{w(H)} t _{w(L)}	(Fig. 1, 2)	2.7	3.0	-	ns
			3.3±0.3	3.0	-	
Minimum Setup Time	t _s	(Fig. 1, 2)	2.7	2.5	-	ns
			3.3±0.3	2.5	-	
Minimum Hold Time	t _h	(Fig. 1, 2)	2.7	1.5	-	ns
			3.3±0.3	1.5	-	
Output to Output Skew	t _{osLH} t _{osHL}	(*10)	2.7	-	-	ns
			3.3±0.3	-	1.0	

(*10) Parameter guaranteed by design. (t_{osLH} = t_{pLHm} - t_{pLHn}, t_{osHL} = t_{pHLm} - t_{pHLn})

Dynamic Switching Characteristics (Ta = 25°C, Input t_r = t_f = 2.5ns, C_L = 50pF, R_L = 500Ω)

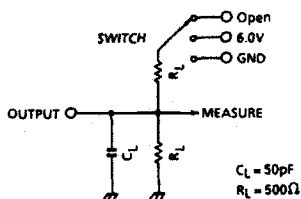
Parameter	Symbol	Test Condition	V _{CC} (V)	Typical	Unit
Quiet Output Maximum Dynamic V _{OL}	V _{OLP}	V _{IH} = 3.3V, V _{IL} = 0V	3.3	0.8	V
Quiet Output Minimum Dynamic V _{OL}	V _{OLV}	V _{IH} = 3.3V, V _{IL} = 0V	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

Parameter	Symbol	Test Condition	V _{CC} (V)	Typical	Unit
Input Capacitance	C _{IN}	-	3.3	7	pF
Bus Input Capacitance	C _{OUT}		3.3	8	pF
Power Dissipation Capacitance	C _{PD}	f _{IN} = 10MHz (*11)	3.3	25	pF

(*11) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I_{CC} (opr.) = C_{PD} • V_{CC} • f_{IN} + I_{CC}/16 (per latch)

Fig.1 Test circuit



Parameter	Switch
t_{pLH}, t_{pHL}	Open
t_{pLZ}, t_{pZL}	6.0V
t_{pHZ}, t_{pZH}	GND
t_w, t_s, t_h, t_{MAX}	Open

AC wave form

Fig.2 $t_{pLH}, t_{pHL}, t_w, t_s, t_h$

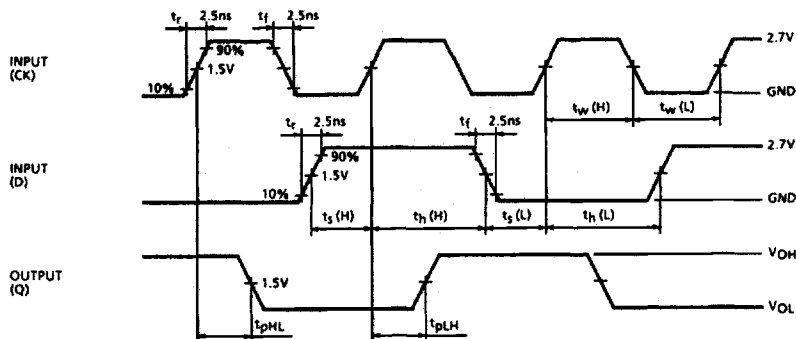
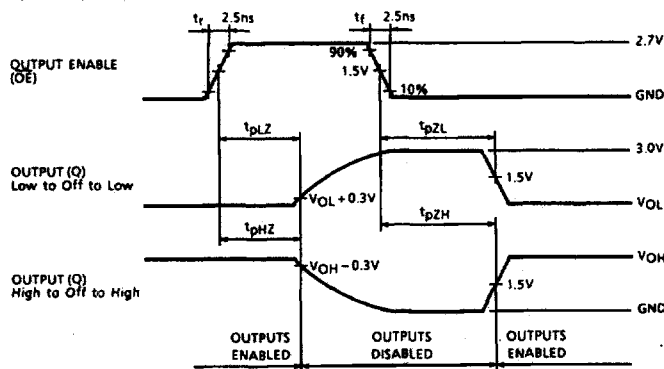


Fig.3 $t_{pLZ}, t_{pHZ}, t_{pZL}, t_{pZH}$



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